

UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.		
10/661,089	09/10/2003	Lee Jen Chen	MXIC-P910270	6595		
7:	590 06/28/2005	EXAMINER				
Stout, Uxa, Buyan & Mullins, LLP 4 Venture, Suite 300 Irvine, CA 92618			HOANG, Q	HOANG, QUOC DINH		
			ART UNIT	PAPER NUMBER		
			2818			
			DATE MAILED: 06/28/2005			

Please find below and/or attached an Office communication concerning this application or proceeding.

								
		Applica	tion No.	Applicant(s)				
Office Action Summary		10/661,	089	CHEN ET AL.	(MU			
		Examin	er	Art Unit				
		Quoc D	-	2818				
Period fo	The MAILING DATE of this commun or Reply	nication appears on t	he cover sheet wi	th the correspondence ad	dress			
THE - Exte after - If the - If NO - Faile Any	ORTENED STATUTORY PERIOD F MAILING DATE OF THIS COMMUN nsions of time may be available under the provision SIX (6) MONTHS from the mailing date of this com e period for reply specified above is less than thirty (o period for reply is specified above, the maximum so are to reply within the set or extended period for repl reply received by the Office later than three months led patent term adjustment. See 37 CFR 1.704(b).	IICATION. s of 37 CFR 1.136(a). In no munication. 30) days, a reply within the statutory period will apply and y will, by statute, cause the a	event, however, may a re tatutory minimum of thirt will expire SIX (6) MON pplication to become AB	eply be timely filed y (30) days will be considered timely THS from the mailing date of this or ANDONED (35 U.S.C. § 133).	y. ommunication.			
Status								
1)[🖂	Responsive to communication(s) fil	ed on <i>02 Mav 2005</i> .						
	This action is FINAL . 2b)⊠ This action is non-final.							
3)	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Disposit	ion of Claims							
5)□ 6)⊠ 7)⊠	 ✓ Claim(s) 1 and 3-17 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. ☐ Claim(s) is/are allowed. ✓ Claim(s) 1 and 3-17 is/are rejected. ✓ Claim(s) 3-5,7-9 and 10 is/are objected to. ☐ Claim(s) are subject to restriction and/or election requirement. 							
Applicat	ion Papers							
10)	The specification is objected to by the training of the drawing (s) filed on is/are Applicant may not request that any objected from the oath or declaration is objected in the specific or declaration is objected to by the specific or declaration is objected to be specific or declaration in the specific or declaration is objected in the specific or declaration in the specific or declaration is objected in the specific or declaration in	e: a) accepted or ection to the drawing(s g the correction is requ) be held in abeyar uired if the drawing	nce. See 37 CFR 1.85(a). (s) is objected to. See 37 Cl				
Priority	under 35 U.S.C. § 119							
а)	Acknowledgment is made of a claim All b) Some * c) None of: 1. Certified copies of the priority 2. Certified copies of the priority 3. Copies of the certified copies application from the Internations See the attached detailed Office actions	y documents have be y documents have be s of the priority docur onal Bureau (PCT R	een received. een received in A ments have been tule 17.2(a)).	pplication No received in this National	Stage			
2) Noti	nt(s) ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (rmation Disclosure Statement(s) (PTO-1449 cer No(s)/Mail Date		Paper No(s	Summary (PTO-413) s)/Mail Date nformal Patent Application (PTO 	O-152)			

DETAILED ACTION

Response to Amendment

1. Amendment filed 05/02/2005 has been entered. In the Amendment, claims 2 and 18-24 have been canceled. Claims 1 and 3-17 are pending in the application.

Applicants' remarks have been considered.

Allowable Subject Matter

2. The indicated allowability of claims 1, 3-5, 7, 9 and 10 are withdrawn in view of the newly discovered reference(s) to Frankel (U.S. Pat No. 5,968,587). Rejections based on the newly cited reference(s) follow.

Claim Objections

3. Claims 3-5, 7-9 and 10 are objected to because of the following informalities:

In claim 3, is that a different between "a phosphosilicate glass layer" in line 4 and "a glass layer" in line 2. If not, the term "a glass layer" in line 2 should be --the phosphosilicate glass layer--, and the term "the glass layer" in line 5 should be --the phosphosilicate glass layer--.

In claim 4, is that a different between "a glass layer" in line 4 and "a glass layer" in line 2. If not, the term "a glass layer" in line 4 should be --the glass layer --.

In claim 5, is that a different between "a glass layer" in line 3 and "a glass layer" in line 2. If not, the term "a glass layer" in line 3 should be --the glass layer --.

In claim 7, is that a different between "a glass layer" in line 4 and "a glass layer" in line 3. If not, the term "a glass layer" in line 4 should be --the glass layer --.

In claim 8, line 1, the term "a cap oxide layer" in line 1 should be --the cap oxide layer --.

In claim 9, is that a different between "a glass layer" in line 3 and "a glass layer" in line 2. If not, the term "a glass layer" in line 3 should be --the glass layer --.

In claim 10, is that a different between "a glass layer" in line 3 and "a glass layer" in line 2. If not, the term "a glass layer" in line 3 should be --the glass layer --.

Appropriate correction is required.

Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. Claims 1 and 3-17, as best understood, are rejected under 35 U.S.C. 103(a) as being unpatentable over Frankel (U.S. Pat No. 5,968,587).

Regarding claim 1, Frankel teaches a method comprising forming an oxide cap 1030 upon a phosphosilicate glass layer 1008 via a chemical vapor deposition process (col. 40, lines 51 through col. 43 line 10 and Fig. 19A and Fig. 19D).

The limitation that the method is "for mitigating defect formation" has not been given patentable weight because it has been held that a preamble in denied the effect of a limitation where the claim following the preamble is a self-contained description of the structure not depending for completeness upon the introductory clause. Kropa v. Robie, 88 USPQ 478 (CCPA 1951).

Regarding claim 3, Frankel teaches a method comprising:

forming a phosphosilicate glass layer 1008 upon a substrate 1004 (col. 40, lines 51 through col. 43 line 10 and Fig. 19A); and

forming an oxide cap 1030 upon the phosphosilicate glass layer 1008 (col. 40, lines 51 through col. 43 line 10 and Fig. 19D).

The limitation that the method is "for mitigating defect formation" has not been given patentable weight because it has been held that a preamble in denied the effect of a limitation where the claim following the preamble is a self-contained description of the structure not depending for completeness upon the introductory clause. Kropa v. Robie, 88 USPQ 478 (CCPA 1951).

Regarding claim 4, Frankel teaches a method comprising:

Application/Control Number: 10/661,089

Art Unit: 2818

forming a glass layer 1008 upon a silicon substrate 1004 (col. 40, lines 51 through col. 43 line 10 and Fig. 19A); and

forming an oxide cap 1030 upon the glass layer 1008 (col. 40, lines 51 through col. 43 line 10 and Fig. 19D).

The limitation that the method is "for mitigating defect formation" has not been given patentable weight because it has been held that a preamble in denied the effect of a limitation where the claim following the preamble is a self-contained description of the structure not depending for completeness upon the introductory clause. Kropa v. Robie, 88 USPQ 478 (CCPA 1951).

Regarding claim 5, Frankel teaches a method comprising:

forming a glass layer 1008 upon a substrate 1004 having at least one semiconductor layer formed theron (col. 40, lines 51 through col. 43 line 10 and Fig. 19A); and

forming a cap oxide 1030 upon the glass layer 1008 (col. 40, lines 51 through col. 43 line 10 and Fig. 19D).

The limitation that the method is "for mitigating defect formation" has not been given patentable weight because it has been held that a preamble in denied the effect of a limitation where the claim following the preamble is a self-contained description of the structure not depending for completeness upon the introductory clause. Kropa v. Robie, 88 USPQ 478 (CCPA 1951).

Regarding claim 6, Frankel teaches forming an oxide cap layer 1030 upon the phosphosilicate glass layer 1008 comprising forming the cap oxide layer 1030 via a chemical vapor deposition process (col. 52, lines 20).

Regarding claim 7, Frankel teaches a method comprising:

forming a glass layer 1008 upon a substrate 1004 via a first chemical vapor deposition process (col. 40, lines 51 through col. 43 line 10 and Fig. 19A); and

forming a cap oxide 1030 upon the glass layer 1008 via a second chemical vapor deposition process, wherein a "reactor" chamber 15 within which the first and second chemical vapor deposition processes are performed is not broken between the first and second chemical vapor deposition processes (col. 40, lines 51 through col. 43 line 10 and Fig. 19A and Fig. 19D).

The limitation the method is "for mitigating defect formation" has not been given patentable weight because it has been held that a preamble in denied the effect of a limitation where the claim following the preamble is a self-contained description of the structure not depending for completeness upon the introductory clause. Kropa v. Robie, 88 USPQ 478 (CCPA 1951).

Regarding claim 8, Frankel teaches wherein forming the cap oxide layer 1030 comprises forming an undoped oxide layer (USG or undoped silicate glass) 1030 upon the glass layer 1008 (col. 42, line 38).

Regarding claim 9, Frankel teaches a method comprising:

forming a glass layer 1008 upon a substrate 1004 (col. 40, lines 51 through col. 43 line 10 and Fig. 19A); and

forming a cap oxide 1030 upon the glass layer 1008, the forming of a cap oxide layer comprising forming an undoped oxide layer (USG) 1030 upon a P-doped oxide film (PSG) 1008 (col. 40, lines 51 through col. 43 line 10 and Fig. 19D).

The limitation that "for mitigating defect formation in a glass layer of a semiconductor device" has not been given patentable weight because it has been held that a preamble in denied the effect of a limitation where the claim following the preamble is a self-contained description of the structure not depending for completeness upon the introductory clause. Kropa v. Robie, 88 USPQ 478 (CCPA 1951).

Regarding claim 10, Frankel teaches a method comprising:

forming a glass layer 1008 upon a substrate 1004 (col. 40, lines 51 through col. 43 line 10 and Fig. 19A); and

forming a cap oxide 1030 upon the glass layer 1008, wherein the glass layer (PSG) 1008 is formed by a process selected from the group consisting of a plasma enhanced chemical vapor deposition process (PECVD) and an sub-atmospheric chemical vapor deposition process (SACVD) (col. 40, lines 51 through col. 43 line 10, col. 47, lines 3-40 and Fig. 19D).

Art Unit: 2818

The limitation that the method is for mitigating defect formation has not been given patentable weight because it has been held that a preamble in denied the effect of a limitation where the claim following the preamble is a self-contained description of the structure not depending for completeness upon the introductory clause. Kropa v. Robie, 88 USPQ 478 (CCPA 1951).

Regarding claim 11, Frankel teaches wherein the cap oxide layer 1030 is formed to have a thickness between about 50-500 Angstroms, but fails to teach wherein the cap oxide layer 1030 having a thickness greater than 300 Angstroms (col. 52, line 5). However, although Frankel's cap oxide layer thickness(50-500 Angstroms) is not in the claimed range (greater than 300 Angstroms), this does not define patenable over Frankel since the thickness is well known processing variable and the discovery of the optimum or workable range involves only routine skill in the art.

Regarding claim 12, Frankel teaches wherein a phosphorus blocking capability of the cap oxide layer is between about 2-8 wt% phosphorus, but fails to teach wherein a phosphorus blocking capability of the cap oxide layer is at least 11% by weight (col. 66, lines 49-51). However, although Frankel's wt % of phosphorus (2-8 wt% phosphorus) is not in the claimed range (11wt% phosphorus), this does not define patenable over Frankel since the concentration of phosphorus in the phosphosilicate glass layer is well known processing variable and the discovery of the optimum or workable range involves only routine skill in the art.

Regarding claim 13, Frankel teaches wherein the cap oxide layer (USG) 1030 is formed by SiH₄ and N₂O reacting gases (col. 50, lines 45-46).

Regarding claim 14, Frankel teaches wherein the cap oxide layer (USG) 1030 is formed by TEOS and 0₂ reacting gases (col. 51, lines 40-45).

Regarding claim 15, Frankel teaches wherein the cap oxide layer 1030 process temperature is between approximately 350°C and approximately 600°C (col. 51, line 32).

Regarding claim 16, Frankel teaches wherein the glass layer 1008 process temperature is between approximately 450°C and approximately 650°C (col. 50, line 34).

Regarding claim 17, Frankel teaches wherein forming the cap oxide layer 1030 comprises forming inter-metal dielectric layers (IMD) (col. 50, lines 22-23).

Conclusion

6. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Quoc Hoang whose telephone number is (571) 272-1780. The examiner can normally be reached on Monday-Friday from 8.00 AM to 5.00 PM.

Art Unit: 2818

If attempt to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David Nelms can be reached on (571) 272-1787. The fax phone numbers of the organization where this application or proceeding is assigned are (703) 872-9306 for regular communications and (703) 872-9306 for After Final communications.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Quoc Hoang

Patent examiner/AU 2818

Guahony 6/17/2005